

SiPM Roadmap

See the recent summaries:

SiMP Summary at the Collaboration Meeting (January 2024):

<https://indico.bnl.gov/event/20473/contributions/84622/attachments/51960/88885/BIC%20SiPM%20Choice%20Intro.pdf>

Follow up on the irradiated SiPMs (from INFN Bologna):

<https://indico.bnl.gov/event/21335/contributions/85608/attachments/52127/89150/BIC%20DCR%20Simulation%201-16-24.pdf>

NOISE

- Dark count rate (DCR) determines threshold
 - MIPs at midrapidity will generate 3-6 N_{pe} on average
 - Would be good to have threshold slightly below MIP
- DCR above a few 10s of MHz will endanger the MIP

Specification	S13360-3050 (3x3 mm)	S14160-3050 (3x3 mm)
DCR (Typ.)	500 kHz	1 MHz***
Crosstalk (%)	3	7

*** Estimated, differing values in literature

- Signal will gang 1.2 cm x 1.2 cm area (16 3x3 mm or 4 6x6 mm)
 - DCR for one BIC channel will be ~16x value in table
- Plan to test S14160 SiPMs at ANL & Regina

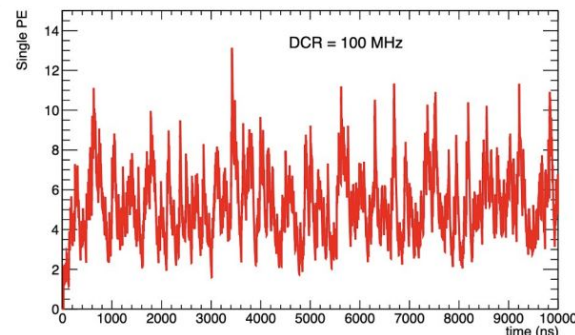
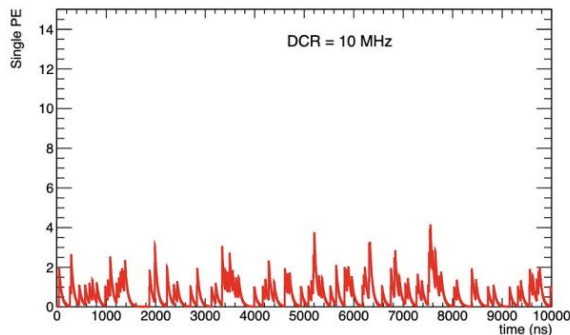
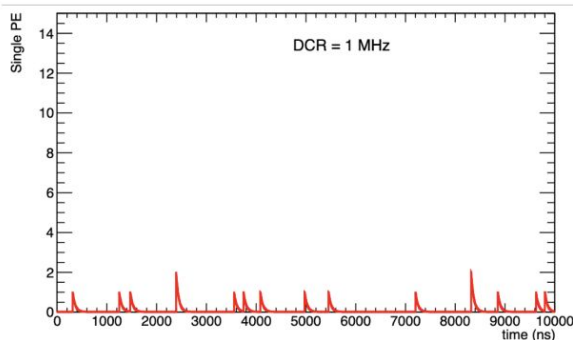


TABLE 1: Barrel Imaging Calorimeter SiPM Specs

Parameter	Specification	Notes
Active Area	3 mm x 3 mm (4 x 4 array)	Preassembled array covering 1.2cm x 1.2cm
Pixel Size	50 μm	
Package Type	Surface Mount	
Peak Sensitivity	450 nm	
PDE	$\sim 50\%$	
Gain	$> \sim 2 \times 10^6$	
DCR	Typ.: $\sim 500\text{kHz}$ / SiPM Max: $< 1.5\text{ MHz}$ / SiPM	DCR applies to each SiPM in the 4 x 4 array
Temperature coefficient of Vop	$< 40\text{mV/C}$	
Direct crosstalk probability	$< \sim 7\%$	
Terminal capacity	$\sim 500\text{pF}$ / SiPM	Applies to each SiPM in the 4 x 4 array
Packing granularity		
Vop variation within a tray	$< 200\text{ mV}$	
Recharge Time	$< 100\text{ ns}$	
Fill Factor	$> 70\%$	
Protective Layer	Silicone (n $\sim 1.5\text{-}1.6$)	

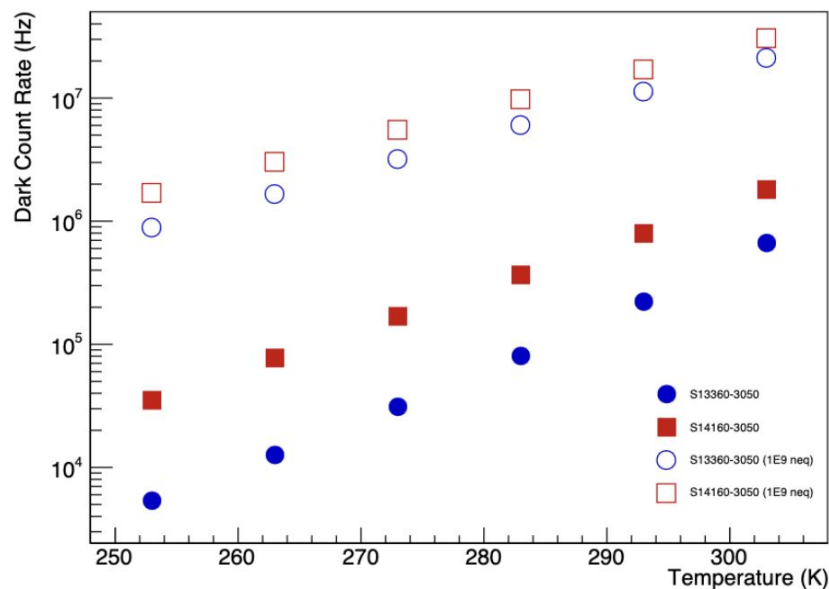
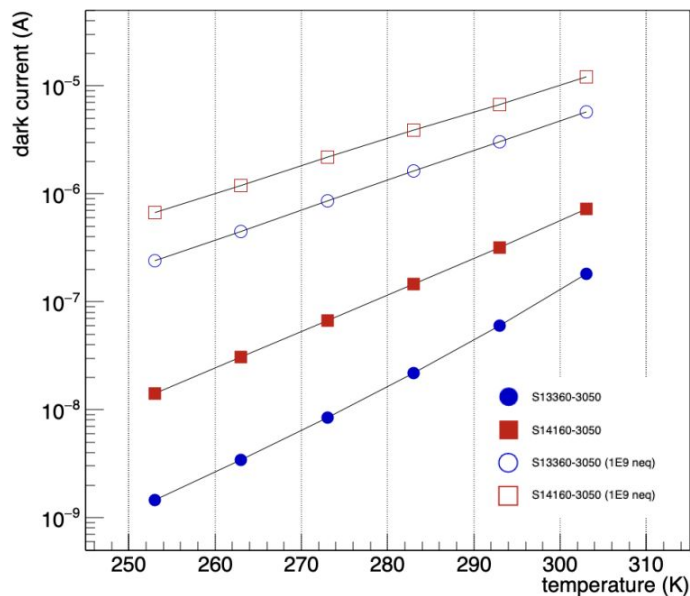
S13360


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S14160

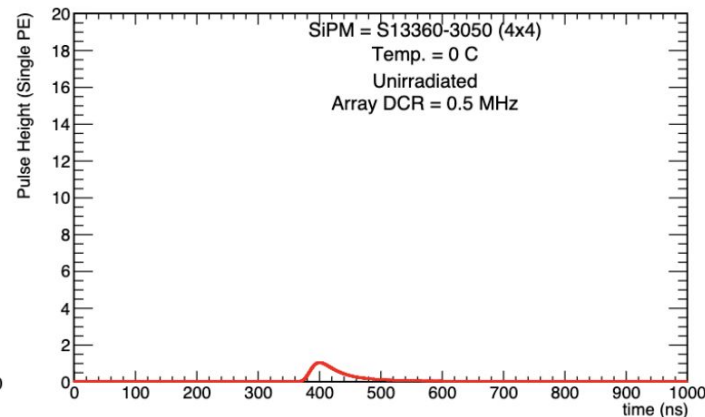
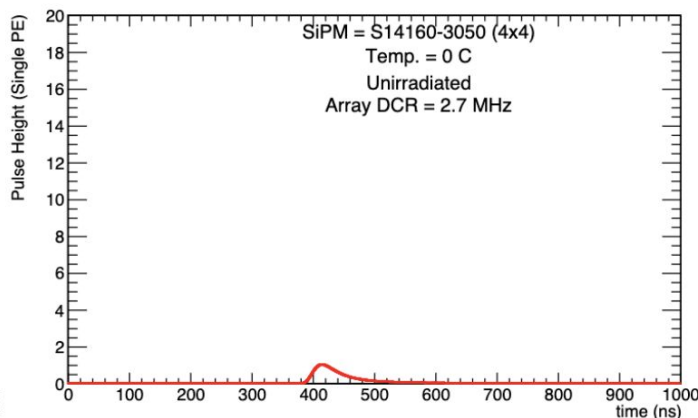
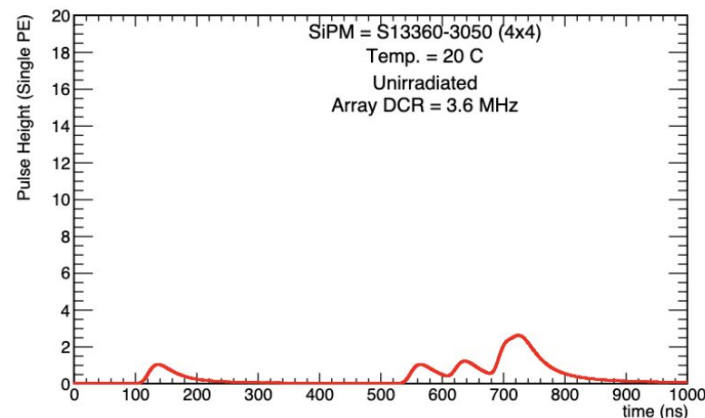
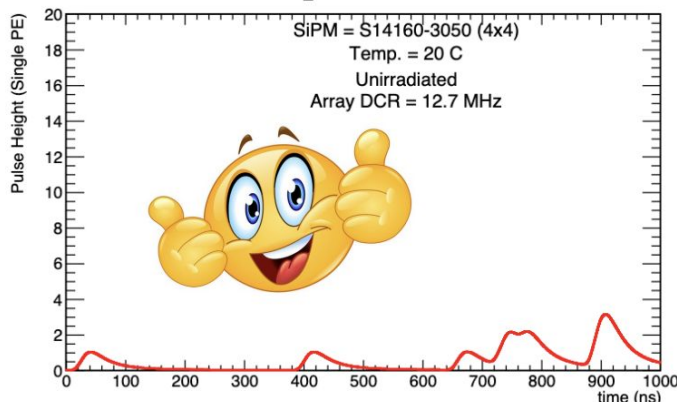

Dark Currents from INFN Measurements

- Scale currents by gain & q_e to get a dark count rate
 - This is a bit naïve, but Roberto indicated it should be alright
- Order of magnitude increase after $1\text{E}9$ 1 MeV neq dose
 - Our conservative estimate of dose for lifetime of experiment was $3\text{E}10$



Temperature Dependence

Both sensors look reasonably good before irradiation, could easily set a threshold at 4 or 5 p.e.

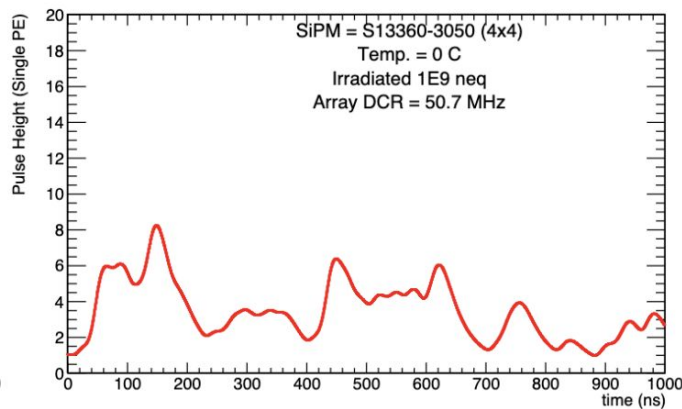
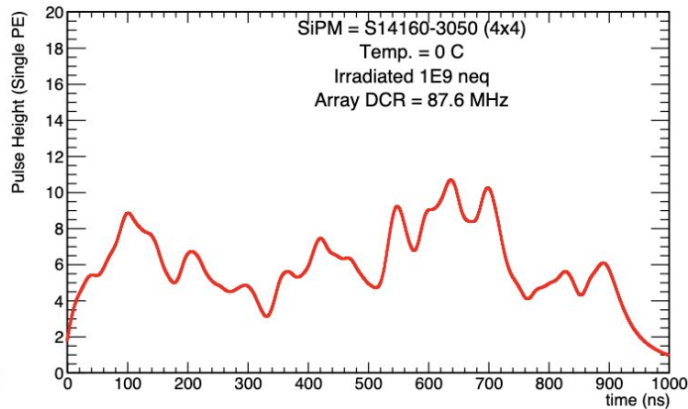
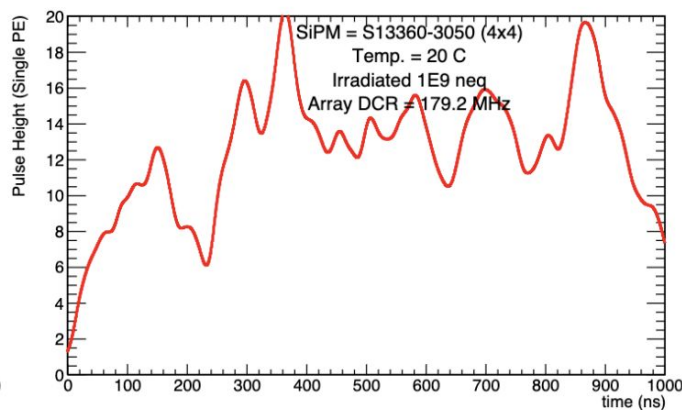
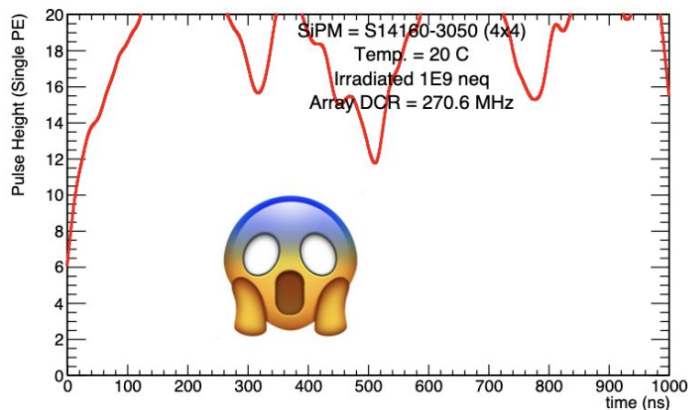


Radiation Damage

0 °C not cool enough to save the MIP for either SiPM after 1E9 1 MeV neq dose

This assumes that the dark *current* produced by irradiation translates directly into dark *counts*, which is the **worst case** scenario

Keep in mind that this represents only ~1/30th of the 10-year expected dose



Roadmap

Question: Which SiMPs are we planning to stick to eventually.

1. SiMPs at hand: S14 (4 6x6 mm and 2 1.2x1.2cm) we can borrow some S13 (6x6 mm at hand)
2. We need to test them very quickly (overlap with ALERT)
3. Irradiation tests (APRIL)